

M21418/M21428 HD/SD and 3G/HD/SD-SDI Cable Drivers

The M21418 and M21428 are high-speed, low-power, low-jitter cable drivers. They are designed to drive serial digital video data through 75 Ω coaxial cable typically used in SMPTE and DVB-ASI video applications. The M21428 cable driver is optimized for performance from 143 Mbps up to 2970 Mbps, the M21418 cable driver is optimized for performance from 143 Mbps up to 1485 Mbps. Both the M21428 and M21418 have selectable slew rates for SD-SDI and HD-SDI applications.

The typical output rise/fall time of the M21428 is 100 ps for HD and 3G rates, the typical output rise/fall time of the M21418 is 100 ps for HD rates. All devices have a typical set slew rate of 600 ps at SD rates. The default output voltage swing is compliant with SMPTE 292M, 259M, 344M and 424M using a 750 Ω ±1% resistor. The M21418 and M21428 are pin compatible. The M21418/M21428 support a maximum single ended output swing of 1600 mVp-p, when configured appropriately.

All devices are packaged in a new high performance 3x3 mm MLF package to simplify the PCB and reduce package parasitics with resulting improvements in Output Return Loss (ORL). Both devices are available in an RoHS compliant package, that is backwards compatible with standard JEDEC SnPb processes.

Applications

- · Serial Routing Switchers,
- · Production/Master Control Switchers
- Distribution Amplifiers
- · Video Tape Recorders, ENG Edit decks, Cameras
- · Broadcast video applications
- NLE's, MPEG Encoders/Decoders, format convertors etc.

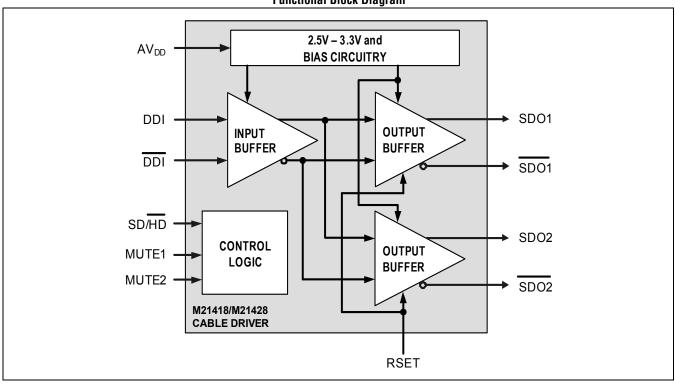
Standards Compliance

- SMPTE 292M, 259M, 344M, 424M (only M21428 complies with 424M)
- DVB-ASI

Features

- 3G, HD and SD operation (M21428),
- HD and SD operation (M21418)
- · Dual Differential outputs, with individual mute control
- 800 mVp-p single ended output swing (typical)
- 1600 mVp-p maximum single ended output swing
- · SD/HD Slew Rate control
- 2.5 V or 3.3 V Supply
- Low P_{DISS} (122 mW @ 2.5 V, 144 mW @ 3.3 V)
- Extended temp. range: -10 to 85 °C
- · RoHS package

Functional Block Diagram





Ordering Information

Part Number	Data Rates Supported	Package	Operating Temperature
M21418G-xx*	143-1485 Mbps	3x3 mm MLF—16pins (RoHS compliant)	-10 °C to 85 °C
M21428G-xx*	143–2970 Mbps	3x3 mm MLF—16pins (RoHS compliant)	-10 °C to 85 °C

NOTES:

Revision History

Revision	Level	Date	Description
Е	Release	July 2013	Removed M21408 part.
			$t_{\mbox{\scriptsize R}}/t_{\mbox{\scriptsize F}}$ maximum in Table 2-7 changed from 180 ps to 135 ps.
			Added Figure 1-4.
			Overshoot/Undershoot increased to +/-10% in Table 2-6 and Table 2-7.
			Removed section on Moisture Sensitivity Level in Section 2.0.
D	Release	May 2007	Modified text in Section 1.1.2 to indicate that RSET must be used.
			SD/HD changed to pull-up in Table 1-5.
С	Release	February 2007	Updated ordering information.
			Minor updates to Tables 2-3, 2-6, and 2-7.
В	Release	February 2007	Production Release
			M21428 added.
			Characterization data added to Tables 2-3, 2-6, and 2-7.
А	Advance	April 2006	Initial Release.

 $^{^{\}star}$ Consult the price list for exact part number when ordering.

^{*} The letter 'G' designator after the part number indicates a RoHS-compliant package. Refer to www.mindspeed.com for additional information.



Table of Contents

Orde	ring li	nformation	. 2
Revis	sion H	listory	. 2
Table	of Co	ontents	. 3
List o	of Figu	ıres	. 4
		les	
1.0		tional Description	
	1.1	Features	
	1.1	1.1.1 HD-SDI and SD-SDI Slew-rate Selection	6
	1.2	1.1.2 Output Amplitude Adjustment	
		1.2.1 High-speed Inputs	7
		1.2.2 High-speed Outputs 1.2.3 M21418/M21428 Pin List	
2.0	Prod	uct Specification	
	2.1	Absolute Maximum Ratings	.10
	2.2	Recommended Operating Conditions	.10
	2.3	DC Electrical Specifications	.11
	2.4	Input/Output Level Specifications	.12
	2.5	Package Specification	.16
		2.5.1 Mechanical Description	
	2.6	Manufactureability	
		2.6.1 Electrostatic Discharge	.18
		2.6.2 Peak Reflow Temperature	.18
	2.7	Design Considerations.	.18
Appe	ndix		19
	A.1	Glossary of Terms/Acronyms	.19
	A.2	Reference Documents	
		A 2.1 External	20



List of Figures

Figure 1-1.	Typical Input Circuit—AC-coupled	7
Figure 1-2.	Typical Input Circuit—DC-coupled	7
Figure 1-3.	Output Matching/Back-termination Circuit (Both Outputs Used)	8
Figure 1-4.	Output Matching/Back-termination Circuit (Only One Output Used)	8
Figure 2-1.	Output Symbols Definition	15
Figure 2-2.	M21418/M21428 Pin Out	16
Figure 2-3.	Package Drawing (3x3 mm MLF Package)1	17



List of Tables

Table 1-1.	Output Swing vs. Supply and Termination Voltage	
Table 1-2.	Interface Pins	
Table 1-3.	Power Pins	
Table 1-4.	High-speed Signal Pins	
Table 1-5.	Control Pins	
Table 2-1.	Absolute Maximum Ratings	10
Table 2-2.	Recommended Operating Conditions	
Table 2-3.	Power DC Electrical Specifications	11
Table 2-4.	CMOS Input Electrical Specifications	12
Table 2-5.	High-Speed Input Electrical Specifications	12
Table 2-6.	Cable Driver Output Electrical Specifications M21418 (SD/HD)	13
Table 2-7.	Cable Driver Output Electrical Specifications M21428 (SD/HD/3G)	14



1.0 Functional Description

1.1 Features

1.1.1 HD-SDI and SD-SDI Slew-rate Selection

The output slew rate of the M21418 and M21428 are selectable to conform with the different SD-SDI and HD-SDI specifications, in the case of the M21428 this includes 3G-SDI. With SD/\overline{HD} = Low, rise/fall time is typically 100 ps. The slew rate will vary depending on the output matching network and connector used.

With **SD/HD** = High, for standard definition (143 to 540 Mbps) applications, the rise/fall time is typically 600 ps, which is compliant with SMPE 259M and SMPTE 344M.

1.1.2 Output Amplitude Adjustment

For SMPTE compliance, an external 750 Ω ±1% resistor at **RSET** to **AV**_{DD} is recommended for a swing level of 800 mV within a tolerance that is less than ±10% which meets SMPTE requirements. The output amplitude can also be adjusted to range from 500 to 1600 mV_{PP} single ended using the following formula:

Output Swing = (600/RSET) [RSET in k Ω] (in mV_{PP}, Single Ended)

The actual swing is set as a function of the IC supply voltage, the external termination voltage and the limitations are shown in Table 1-1. For a 3.3 V minimum termination voltage, the IC can be SMPTE compliant for all supply voltages. In applications where lossy matching or splitting networks are used, the M21418/M21428 offers additional gain of up to 1600 mV_{PP} swings. When using swings in excess of 1200 mV, there will be an increase in rise and fall times.

Table 1-1. Output Swing vs. Supply and Termination Voltage

AV _{DD} (V)	AV _{DDTERM} (V)	Maximum Swing (Single-ended mVp-p)	Minimum Swing (Single-ended mVp-p)
2.5-3.3 V	3.3 V	1200 mV	500 mV
2.5–3.3 V	5.0 V	1600 mV	500 mV



1.2 Pin Definitions

1.2.1 High-speed Inputs

The M21418/M21428 are designed to be operated with input signals as low as 100 mV or up to 2000 mV differential peak to peak. The M21418/M21428 uses external 50 Ω input termination resistors to match 100 Ω differential impedance transmission lines for improved system level performance. The M21418/M21428 recommended input circuits are shown in Figure 1-1.

Note that AC-coupling is not required when the M21418/M21428 are driven by Mindspeed Broadcast video devices.

Figure 1-1. Typical Input Circuit—AC-coupled

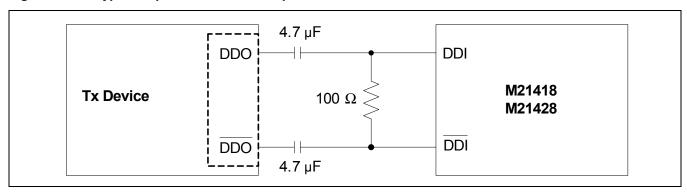
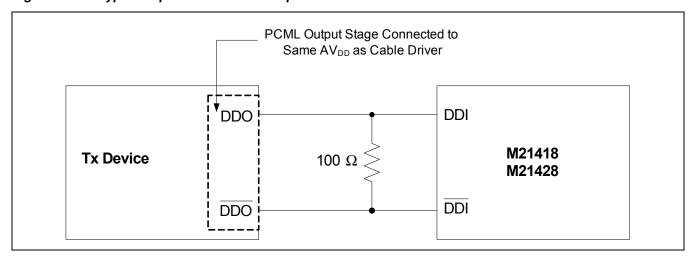


Figure 1-2. Typical Input Circuit—DC-coupled





1.2.2 High-speed Outputs

The M21418/M21428 output buffer is an open collector buffer that is designed for a return loss of 15 dB at SD and HD rates and 10 dB at 3G rates, using standard through-hole BNC connectors as typically employed in broadcast video equipment. A typical output matching circuit is shown in Figure 1-3. The Output Return Loss (ORL) is dependent on many factors such as the value and type of components used, PCB layout, PCB trace lengths, and type of PCB di-electric, therefore, the recommendations in the figure below should be used as starting guidelines only. Different output matching network topologies and different component values will result in different ORL performance.

The M21418/M21428 has SD-SDI and HD-SDI rise/fall times that are typically faster than the legacy cable driver devices but within the relevant SMPTE specification for additional margin in most designs. The faster output slew rate results in a more open eye. The actual maximum output of the part depends on the applied IC voltage as well as the external termination voltage for the load termination. The limitations are discussed in Section 1.1.

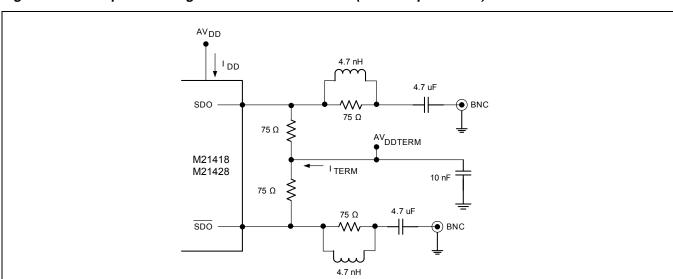
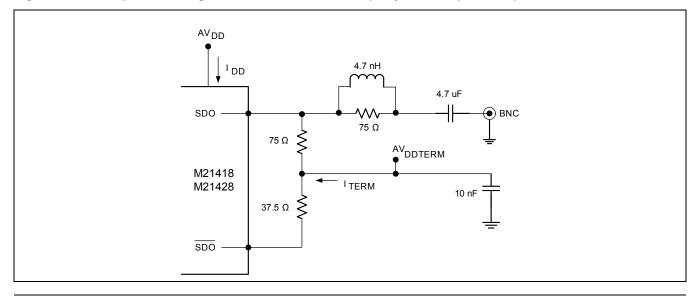
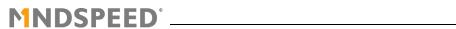


Figure 1-3. Output Matching/Back-termination Circuit (Both Outputs Used)

Figure 1-4. Output Matching/Back-termination Circuit (Only One Output Used)





1.2.3 M21418/M21428 Pin List

Table 1-2. Interface Pins

Pin Name	Pin #	Function	Default	Type
RSET	5	Input control signal for setting the single-ended output swing amplitude.	_	Analog Input
		Higher output swing levels or reduced variations with a $\pm 1\%$ tolerance external resistor.		
		For 800mVp–p single-ended, a 750 Ω ±1% resistor to AV _{DD} is recommended.		

Table 1-3. Power Pins

Pin Name	Pin#	Function	Туре
AV _{SS}	3, 8, 15	Chip Ground	Power
AV _{DD}	2, 7	Positive Supply	Power
NC	4	Not Connected. Leave these pins floating. Do not connect to any supply, ground or logic level.	NC

Table 1-4. High-speed Signal Pins

Pin Name	Pin#	Function	Default	Type
DDI/DDI	16, 1	Non-inverting and Inverting serial externally terminated inputs.	_	I—High-speed
SD02/SD02	11, 10	Non-inverting and inverting serial unterminated data outputs to coaxial cable.	_	0—High-speed
SD01/SD01	13, 12	Non-inverting and inverting serial unterminated data outputs to coaxial cable.	_	0—High-speed

Table 1-5. Control Pins

Pin Name	Pin#	Function	Default	Type
MUTE2	6	A high mutes SD02/SD02 outputs, low enables SD02/SD02.	Pull-up	I—CMOS
MUTE1	14	A high mutes SD01/SD01 outputs, low enables SD01, SD01.	Pull-down	I—CMOS
SD/HD	9	Input control signal to change the output slew rate. SD/HD = High: Slow output slew rate for SD-SDI rate (143–540 Mbps). SD/HD = Low: Fast output slew rate for HD and 3G-SDI rate.	Pull-up	I—CMOS
NOTES:				

Internal pull-ups/pull-downs are 100 k Ω .



2.0 Product Specification

2.1 Absolute Maximum Ratings

Table 2-1. Absolute Maximum Ratings

Symbol	Parameter	Minimum	Maximum	Units
V _{DD}	Power	AV _{SS} - 0.5	AV _{SS} + 3.47	V
V _{IOAM}	Any I/O Pin	AV _{SS} - 0.5	AV _{DD} + 0.5	V
T _{STORE}	Storage Temperature	-65	+150	°C
ESD _{HBML}	Human Body Model (low-speed)	2000	_	V
ESD _{HBMH}	Human Body Model (high-speed outputs)	2000	_	V
ESD _{CDM}	Charge Device Model	500	_	V

NOTE:

2.2 Recommended Operating Conditions

Table 2-2. Recommended Operating Conditions

Symbol	Parameter	Notes	Minimum	Typical	Maximum	Units
AV_DD	AV _{DD} Power	1	_	2.5/3.3	_	V
AV _{SS}	AV _{SS} Ground	_	_	0	_	V
T _A	Ambient Temperature	_	-10	_	+85	°C
θ_{JA}	Junction to ambient Thermal Resistance	2, 3	_	75	_	°C/W
AV _{DD_TERM}	75 Ω Output Termination Voltage	See Table 1-1.				

- ±5% is allowed from nominal supply.
- Solder exposed underbody paddle with an array of thermal vias to optimize junction to ambient thermal resistance. Refer to Amkor Application Note (see Section A.2.1).
- 3. Mounted on a multi layer board (≥ 4 layers), airflow = 0.0 m/s.

^{1.} No Damage.



2.3 DC Electrical Specifications

Table 2-3. Power DC Electrical Specifications

Parameter	Notes	Minimum	Typical	Maximum	Units
Supply Current (one output enabled)	1, 2	_	27	36	mA
Supply Current (two outputs enabled)	1, 2	_	48	_	mA
Current in external termination resistors	1, 2, 3	_	22	_	mA
Power dissipation (AV _{DD} = 2.5 V, AV _{DDTERM} = 3.3 V)	1, 2, 4, 7	_	122	_	mW
Power dissipation (AV _{DD} = 2.5 V, AV _{DDTERM} = 3.3 V)	1, 2, 5, 7	_	156	_	mW
Power dissipation (AV _{DD} = 2.5 V, AV _{DDTERM} = 5.0 V)	1, 2, 4, 7	_	159	_	mW
Power dissipation (AV _{DD} = 2.5 V, AV _{DDTERM} = 5.0 V)	1, 2, 5, 7	_	194	_	mW
Power dissipation (AV _{DD} = 3.3 V, AV _{DDTERM} = 3.3 V)	1, 2, 4, 7	_	144	_	mW
Power dissipation (AV _{DD} = 3.3 V, AV _{DDTERM} = 3.3 V)	1, 2, 5, 7	_	195	_	mW
Power dissipation (AV _{DD} = 3.3 V, AV _{DDTERM} = 5.0 V)	1, 2, 4, 7	_	181	_	mW
Power dissipation (AV _{DD} = 3.3 V, AV _{DDTERM} = 5.0 V)	1, 2, 5, 7	_	232	_	mW
Power dissipation (AV _{DD} = 2.5 V, AV _{DDTERM} = 3.3 V)	1, 2, 4, 6	_	140	_	mW
Power dissipation (AV _{DD} = 2.5 V, AV _{DDTERM} = 3.3 V)	1, 2, 5, 6	_	193	_	mW
Power dissipation (AV _{DD} = 2.5 V, AV _{DDTERM} = 5.0 V)	1, 2, 4, 6	_	177	_	mW
Power dissipation (AV _{DD} = 2.5 V, AV _{DDTERM} = 5.0 V)	1, 2, 5, 6	_	230	_	mW
Power dissipation (AV _{DD} = 3.3 V, AV _{DDTERM} = 3.3 V)	1, 2, 4, 6	_	162	_	mW
Power dissipation (AV _{DD} = 3.3 V, AV _{DDTERM} = 3.3 V)	1, 2, 5, 6	_	231	_	mW
Power dissipation (AV _{DD} = 3.3 V, AV _{DDTERM} = 5.0 V)	1, 2, 4, 6	_	199	_	mW
Power dissipation (AV _{DD} = 3.3 V, AV _{DDTERM} = 5.0 V)	1, 2, 5, 6	_	268	_	mW
	Supply Current (one output enabled) Supply Current (two outputs enabled) Current in external termination resistors Power dissipation (AV _{DD} = 2.5 V, AV _{DDTERM} = 3.3 V) Power dissipation (AV _{DD} = 2.5 V, AV _{DDTERM} = 3.3 V) Power dissipation (AV _{DD} = 2.5 V, AV _{DDTERM} = 5.0 V) Power dissipation (AV _{DD} = 2.5 V, AV _{DDTERM} = 5.0 V) Power dissipation (AV _{DD} = 3.3 V, AV _{DDTERM} = 3.3 V) Power dissipation (AV _{DD} = 3.3 V, AV _{DDTERM} = 3.3 V) Power dissipation (AV _{DD} = 3.3 V, AV _{DDTERM} = 5.0 V) Power dissipation (AV _{DD} = 3.3 V, AV _{DDTERM} = 5.0 V) Power dissipation (AV _{DD} = 2.5 V, AV _{DDTERM} = 3.3 V) Power dissipation (AV _{DD} = 2.5 V, AV _{DDTERM} = 3.3 V) Power dissipation (AV _{DD} = 2.5 V, AV _{DDTERM} = 5.0 V) Power dissipation (AV _{DD} = 2.5 V, AV _{DDTERM} = 5.0 V) Power dissipation (AV _{DD} = 3.3 V, AV _{DDTERM} = 5.0 V) Power dissipation (AV _{DD} = 3.3 V, AV _{DDTERM} = 3.3 V) Power dissipation (AV _{DD} = 3.3 V, AV _{DDTERM} = 3.3 V) 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- 1. Recommended operating conditions—see Table 2-2.
- 2. 800 mV standard SMPTE swing, terminated as in Figure 1-3.
- 3. A portion of the power will be dissipated in the external 7500hm termination ($P_{EXT} = V_{OD} \times I_{TERM}$).
- 4. One Output Enabled.
- 5. Two Outputs Enabled.
- 6. $P_{DISSTOT} = AV_{DD} \times I_{DD} + AV_{DDTERM} \times I_{TERM}$
- 7. $P_{DISSINT} = P_{DISSTOT} P_{EXT}$



2.4 Input/Output Level Specifications

Table 2-4. CMOS Input Electrical Specifications

Symbol	Parameter	Notes	Minimum	Typical	Maximum	Units
V _{IH}	Input Logic High Voltage	1	0.75 x AV _{DD}	_	AV _{DD} + 0.3	V
V _{IL}	Input Logic Low Voltage	1	0	_	0.25 x AV _{DD}	V
I _{IH}	Input Current (logic High)	1	-100	_	100	μА
I _{IL}	Input Current (logic Low)	1	-100	_	100	μА

NOTE:

Table 2-5. High-Speed Input Electrical Specifications

Symbol	Parameter	Notes	Minimum	Typical	Maximum	Units
DR _{IN}	Input Bit Rate (M21418)	1, 2	0	_	1485	Mbps
DR _{IN}	Input Bit Rate (M21428)	1, 2	0	_	2970	Mbps
V _{ID}	Input Differential Voltage (peak to peak)	1, 3, 4	100	_	2000	mV
V _{CM}	Input Common-Mode Voltage	1	1200	_	AV_DD	mV
V _{IH}	Maximum Input High Voltage	1	_	_	AV _{DD} + 400	mV
V _{IL}	Minimum Input Low Voltage	1	1.2	_	_	V
R _{IN}	Single-ended input impedance	1	_	13.33	20	kΩ

- 1. Specified at recommended operation conditions—see Table 2-2.
- 2. Part is DC-coupled at the input.
- 3. Example 1200 mV_{PP} differential = 600 mV_{PP} for each single-ended terminal.
- 4. Minimum input level defined as BER $\leq 10^{-12}$.

^{1.} Specified at recommended operating condition—see Table 2-2.



Table 2-6. Cable Driver Output Electrical Specifications M21418 (SD/HD)

Symbol	Parameter	Notes	Minimum	Typical	Maximum	Units
DR _{OUT}	Output Bit Rates	1, 5	_	_	1485	Mbps
t _R /t _F	SD Rise/Fall Time (20–80%)	1, 3	400	600	800	ps
	HD Rise/Fall Time (20–80%)	1, 3	_	100	135	ps
t _R /t _{fMM}	Rise/fall mismatch (HD Rate)	1, 2	_	10	30	ps
	Rise/fall mismatch (SD Rate)	1, 2	_	40	100	ps
V _{OD}	Single-ended voltage swing range p-p	1, 2, 4, 5	500	800	1600	mV
V _{ODTOL}	Swing Level output variation at 800 mV _{PP} [RSET = 750 Ω ±1%] (Single-Ended)	1, 2, 3	-7	_	+7	%
V _{OS}	Overshoot/Undershoot	1, 2	-10	_	+10	%
JAO _{PP}	Additive Output Jitter (HD rate 1010 pattern)	1, 8	_	20	30	ps
	Additive Output Jitter (SD rate 1010 pattern)	1, 8	_	40	60	ps
DCD ₀	Duty Cycle Distortion (HD Rate)	1, 2, 6, 8	_	15	30	ps
	Duty Cycle Distortion (SD Rate)	1, 2, 6, 8	_	20	70	ps
S ₂₂	Output Return Loss (5 MHz to 1.5 GHz)	1, 2, 7	15	_	_	dB

- Entire table specified at recommended operating condition with 400 mV_{P-P} differential input—see Table 2-2.
- 2. Specification verified at 800 mV_{PP} output with 1 m cable on MSPD test board. System results may vary.
- 3. Rated at nominal SMPTE 800 mV output swing level (using a 750 Ω ±1% resistor at RSET).
- 4. Output stage is an open collector differential pair, actual swing dependant on IC supply voltage and external termination voltage.
- 5. Into 75 Ω back termination and 75 Ω load and appropriate external termination voltage.
- 6. Duty Cycle Distortion (DCD) is defined as the difference in the intrinsic jitter at the 50% voltage level and the intrinsic jitter at the rising/falling edge crossing point. If the rising/falling edge crossing point is at the 50% voltage level, then DCD = 0.
- 7. Measured under DC conditions that simulate AC-coupling, $V_T = 3.3 \text{ V}$.
- 8. Measured using a "1010" data pattern.



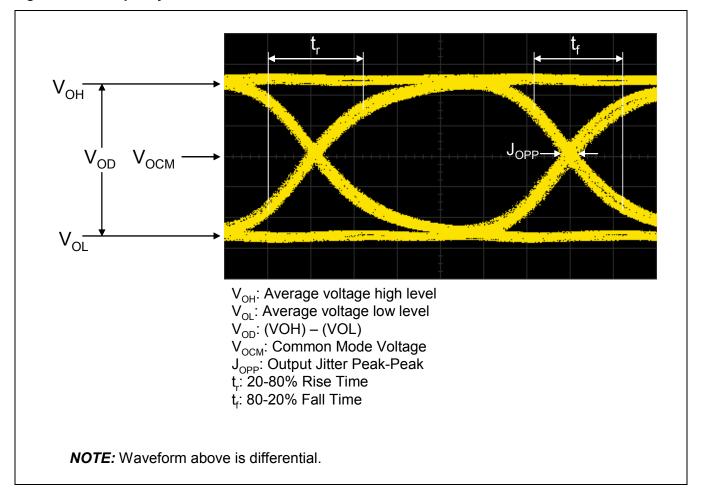
Table 2-7. Cable Driver Output Electrical Specifications M21428 (SD/HD/3G)

Symbol	Parameter	Notes	Minimum	Typical	Maximum	Units
DR _{OUT}	Output Bit Rates	1, 5	_	_	2970	Mbps
t _R /t _F	SD Rise/Fall Time (20–80%)	1, 3, 5	400	600	800	ps
	HD/3G Rise/Fall Time (20-80%)	1, 3, 5	_	100	135	ps
t _R /t _{fMM}	Rise/fall mismatch (HD/3G Rate)	1, 2, 5	_	10	30	ps
	Rise/fall mismatch (SD Rate)	1, 2, 5	_	40	100	ps
V ₀	Single-ended voltage swing range p-p	1, 2, 4, 5	500	800	1600	mV
V _{OTOL}	Swing Level output variation at 800 mV _{PP} [RSET = 750 Ω ±1%] (Single-Ended)	1, 2, 3, 5	-7	_	+7	%
V _{OS}	Overshoot/Undershoot	1, 2, 5	-10	_	+10	%
JAO _{PP}	Additive Output Jitter (HD/3G rate)	1, 5, 8	_	20	30	ps
	Additive Output Jitter (SD rate)	1, 5, 8	_	40	60	ps
DCD ₀	Duty Cycle Distortion (HD/3G Rate)	1, 2, 5, 6, 8	_	15	30	ps
	Duty Cycle Distortion (SD Rate)	1, 2, 5, 6, 8	_	20	70	ps
S ₂₂	Output Return Loss (5 MHz to 1.5 GHz)	1, 2, 5, 7	15	_	_	dB
S ₂₂	Output Return Loss (5 MHz to 3.0 GHz)	1, 2, 5, 7	10	_	_	dB

- Entire table specified at recommended operating condition with 400 mV_{P-P} differential input—see Table 2-2.
- 2. Specification verified at 800 mV_{PP} output with 1 m cable on MSPD test board. System results may vary.
- 3. Rated at nominal SMPTE 800 mV output swing level (using a 75 Ω ±1% resistor at RSET).
- 4. Output stage is an open collector differential pair, actual swing dependant on IC supply voltage and external termination voltage.
- 5. Into 75 Ω back termination and 75 Ω load and appropriate external termination voltage, see Table 1-1, Figure 1-3.
- 6. Duty Cycle Distortion (DCD) is defined as the difference in the intrinsic jitter at the 50% voltage level and the intrinsic jitter at the rising/falling edge crossing point. If the rising/falling edge crossing point is at the 50% voltage level, then DCD = 0.
- 7. Measured under DC conditions that simulate AC-coupling, $V_T = 3.3 \text{ V}$.
- 8. Measured using a "1010" data pattern.



Figure 2-1. Output Symbols Definition





2.5 Package Specification

2.5.1 Mechanical Description

2.5.1.1 Package Information

The M21418/M21428 are available in a 16-pin, 3x3 mm MLF IC package. The pin out is shown in Figure 2-2 and the package drawing in Figure 2-3.

Figure 2-2. M21418/M21428 Pin Out

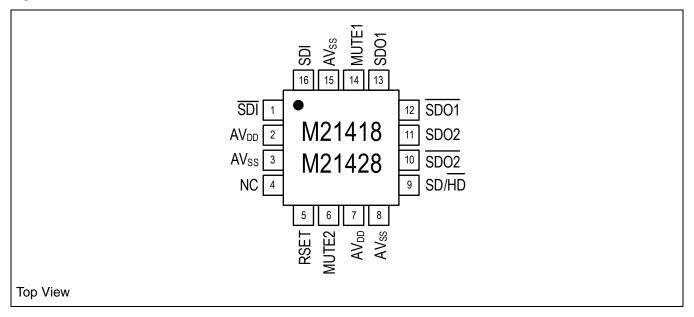
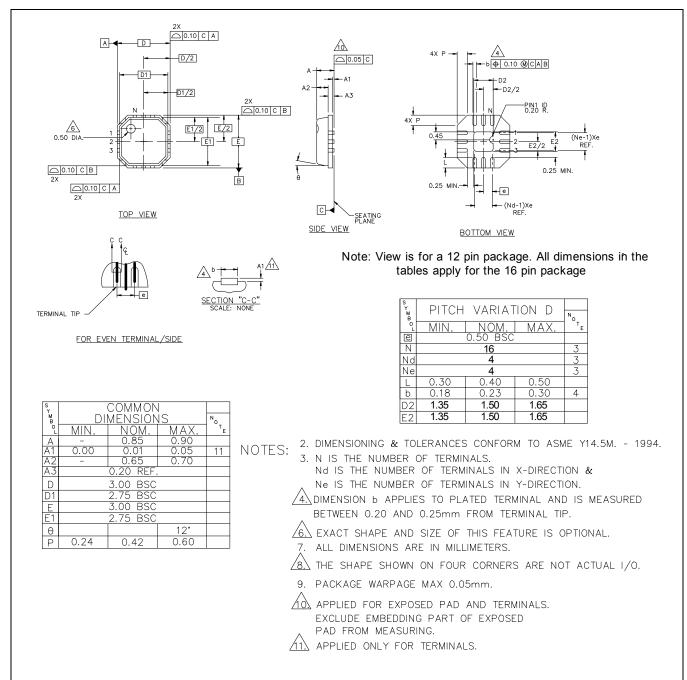




Figure 2-3. Package Drawing (3x3 mm MLF Package)¹



1. Please see Amkor's Application Note for PCB footprint (referenced in Section 3.2.1).



2.6 Manufactureability

The values shown in this section may change; however, these are standard requirements.

2.6.1 Electrostatic Discharge

Tested per JESD22-A114. This device passes 2000 V of ESD Human Body Model (HBM) testing.

Tested per JESD22-C101. This device passes 500 V of ESD Charged Device Model (CDM) testing.

Tested per EIA/JESD78. This device passes 150 mA of trigger current at 85 °C during Latchup testing.

2.6.2 Peak Reflow Temperature

M21418/M21428G (RoHS compliant package): Peak reflow temperature is 260 °C per JEDEC standards.

2.7 Design Considerations

See Digital Video Interfacing Application Note (212xx-APP-001-A) for guidance on the following:

- Component Placement and Layout
- Routing Considerations and Thermal Considerations

The M21418/M21428 consumes less power than legacy devices, therefore the M21418/M21428 will contribute less thermal energy resulting in a lower operating temperature.



Appendix

A.1 Glossary of Terms/Acronyms

BER Bit Error Rate
CD Cable Driver

CDA Cable Distribution Amplifier

CML Current Mode Logic

CMOS Complementary Metal Oxide Semiconductor

DPLL Digital Phase Locked Loop

DTV Digital Television

DVB Digital Video Broadcast

EMI Electro Magnetic Interference

EQ Equalizer or Equalization

GREEN Environmentally friendly

HD High Definition

HW Hardware

IC Integrated Circuit

ID Identifier

I/O Input/Output

MLF Micro Lead Frame package (also called QFN)

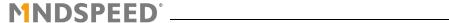
PCB Printed Circuit Board
ORL Output Return Loss

RoHS Restriction of Hazardous Substances

SD Standard Definition
SDI Serial Digital Input
SDO Serial Digital Output

SE Single Ended

SMPTE Society of Motion Picture and Television Engineers



A.2 Reference Documents

A.2.1 External

The following external documents were referenced in this data sheet.

- Application Notes for Surface Mount Assembly of Amkor's MicroLeadFrame (MLF) Packages
- Amkor Technology Thermal Test Report TT-00-06 (See http://www.amkor.com for detailed information)
- SMPTE 292M, SMPTE 259M, SMPTE 344M
- ESI t_R101 891 DVB Asynchronous Serial Interface (ASI)



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